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FDS6692A N-Channel PowerTrench[®] MOSFET 30V, 9A, 11.5mΩ

Features

- $R_{DS(ON)} = 11.5m\Omega$, $V_{GS} = 10V$, $I_D = 9A$
- R_{DS(ON)} = 14.5mΩ, V_{GS} = 4.5V, I_D = 8.2A
- High performance trench technology for extremely low R_{DS(ON)}
- Low gate charge
- High power and current handling capability
- RoHS Compliant

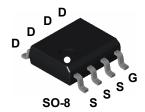
Applications

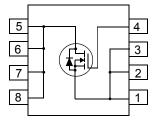
DC/DC converters

General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.







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Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	30	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current		
	Continuous ($T_A = 25^{\circ}C$, $V_{GS} = 10V$, $R_{\theta JA} = 85^{\circ}C/W$)	9	Α
D	Continuous ($T_A = 25^{\circ}C$, $V_{GS} = 4.5V$, $R_{\theta JA} = 85^{\circ}C/W$)	8.2	Α
	Pulsed	48	Α
E _{AS}	Single Pulse Avalanche Energy (Note 1)	79	mJ
P _D	Power dissipation	1.47	W
TJ, T _{STG}	Operating and Storage Temperature	-55 to 150	°C

H_{0JA} I hermal Hesistance, Junction to Ambient at 10 seconds (Note 3) 50 R_{0JA} Thermal Resistance, Junction to Ambient at 1000 seconds (Note 3) 85

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS6692A	FDS6692A	SO-8	330mm	12mm	2500 units

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Charac	cteristics					

B _{VDSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	30	-	-	V
$\Delta B_{VDSS} \Delta T_J$	Breakdown Voltage Temp. Coefficient	$I_D = 250\mu A$, Referenced to $25^{\circ}C$	-	21	-	mV/ºC
1	Zero Gate Voltage Drain Current	V _{DS} = 24V	-	-	1	μA
DSS	Zero Gate voltage Drain Current	$V_{GS} = 0V$ $T_J = 15$	50°C -	-	250	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA

On Characteristics

V _{GS(TH)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	1.2	-	2.5	V
$\frac{\Delta V_{GS(TH)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, Referenced to $25^{\circ}C$	-	-5	-	mV/ºC
	Drain to Source On Resistance	I _D = 9A, V _{GS} = 10V	-	8.2	11.5	
R _{DS(ON)}		I _D = 8.2A, V _{GS} = 4.5V	-	11	14.5	mΩ
20(011)		$I_D = 9A, V_{GS} = 10V,$ $T_J = 150^{\circ}C$	-	13	19	- 1115.2

Dynamic Characteristics

CISS	Input Capacitance			-	1210	1610	pF
C _{OSS}	Output Capacitance	$V_{DS} = 15V, V_{GS}$ = 1 MHz	= 0V,	-	330	440	pF
C _{RSS}	Reverse Transfer Capacitance			-	138	210	pF
R _G	Gate Resistance	f = 1MHz		-	2.0	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0V to 10V		-	22	29	nC
Q _{g(5)}	Total Gate Charge at 5V	$V_{GS} = 0V$ to 5V	V _{DD} = 15V	-	12	16	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{GS} = 0V$ to 1V	I _D = 9A	-	0.93	1.2	nC
Q _{gs}	Gate to Source Gate Charge		l _g = 1.0mA	-	3	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau			-	2.1	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	4.8	-	nC

°C/W

Switchir	ng Characteristics (V _{GS} = 10V)					
t _{ON}	Turn-On Time		-	-	60	ns
t _{d(ON)}	Turn-On Delay Time		-	8	-	ns
t _r	Rise Time	V _{DD} = 15V, I _D = 9A	-	32	-	ns
t _{d(OFF)}	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 6.2\Omega$	-	33	-	ns
t _f	Fall Time		-	13	-	ns
t _{OFF}	Turn-Off Time		-	-	69	ns

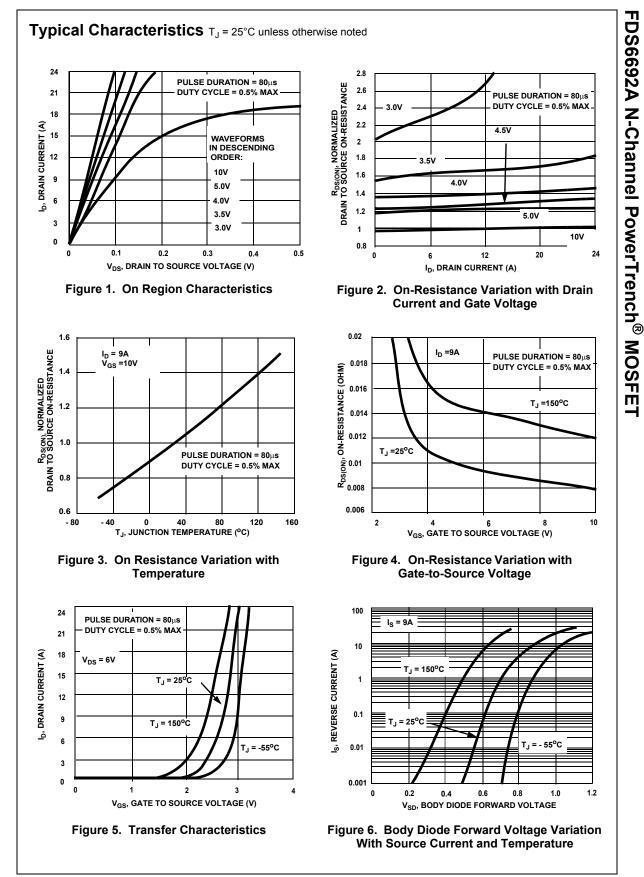
Drain-Source Diode Characteristics

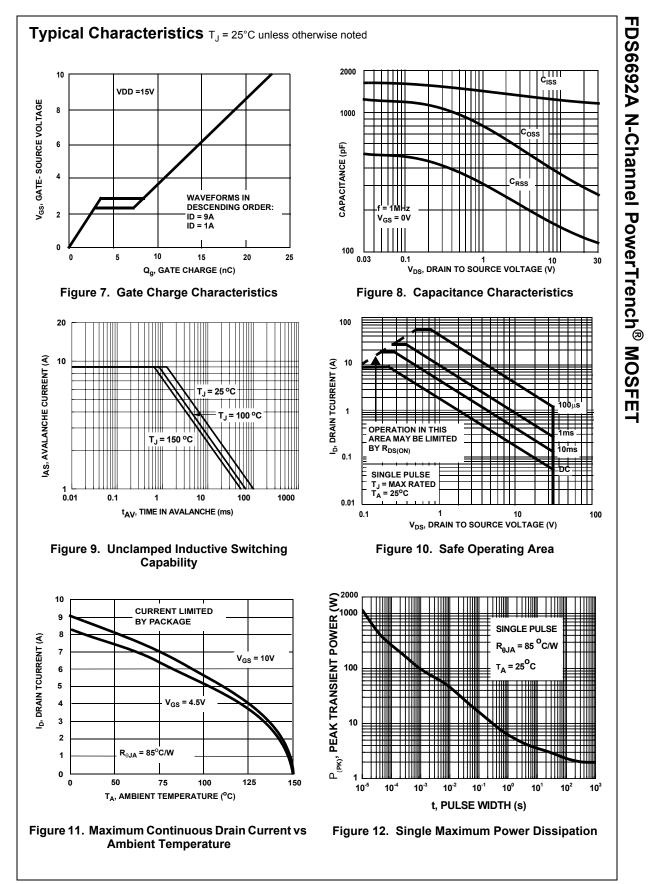
V.	Source to Drain Diode Voltage	I _{SD} = 9A	-	-	1.25	V
V _{SD} Source to Drain Diode Voltage	I _{SD} = 2.1A	-	-	1.0	V	
t _{rr}	Reverse Recovery Time	$I_{SD} = 9A$, $dI_{SD}/dt = 100A/\mu s$	-	-	27	ns
Q _{RR}	Reverse Recovered Charge	$I_{SD} = 9A, dI_{SD}/dt = 100A/\mu s$	-	-	17	nC

Notes:

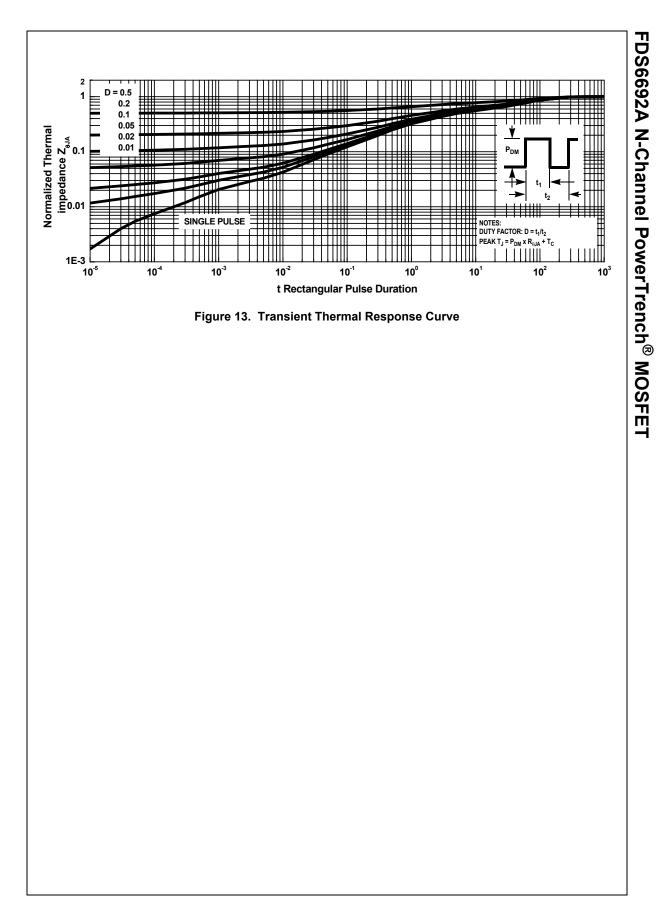
1: Starting T_J = 25°C, L = 0.3mH, I_{AS} = 23A, V_{DD} = 27V, V_{GS} = 10V.
2: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design while R_{0JA} is determined by the user's board design.
3: R_{0JA} is measured with 1.0 in² copper on FR-4 board

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